

## Schottky Barrier Diode

### Features

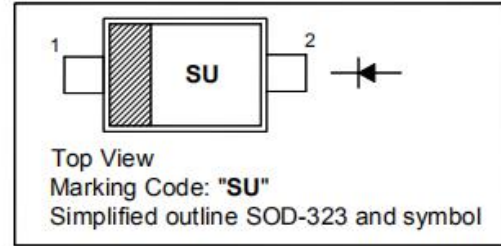
- Low forward voltage
- Low reverse current

### Applications

- High Speed Switching

### PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



### Absolute Maximum Ratings ( $T_a = 25\text{ }^\circ\text{C}$ )

Parameter	Symbol	Limit	Unit
Peak reverse voltage	$V_{RM}$	45	V
DC reverse voltage	$V_R$	40	v
Mean rectifying current	$I_O$	0.1	A
Non-repetitive Peak Forward Surge Current@ $t=8.3\text{ms}$	$I_{FSM}$		1 A
Power dissipation	$P_D$	200	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	500	C/W
Operating Junction Temperature Range	$T_j$	-40 ~ +125	C
Storage Temperature Range	$T_{stg}$	-55 ~ +150	C

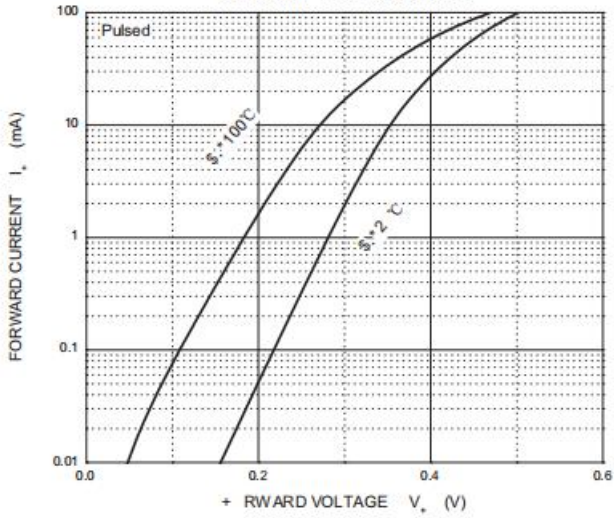
### Electrical Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ )

Forward voltage	$V_F$			0.35	V	$I_F=1\text{mA}$
Forward voltage	$V_F$			0.45	v	$I_F=10\text{mA}$
Forward voltage	$V_F$			0.60	v	$I_F=100\text{mA}$
Reverse current	$I_R$			5	$\mu\text{A}$	$V_R=40\text{V}$
Capacitance between terminals	$C_T$			25	pF	$V_R=0\text{V}, f=1\text{MHz}$

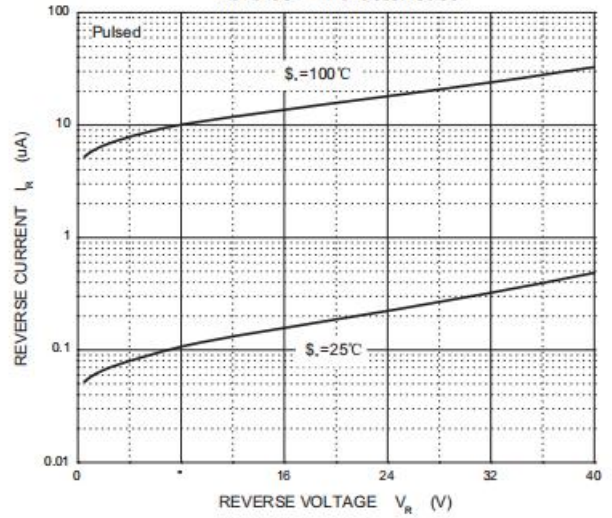


### Typical Characteristics

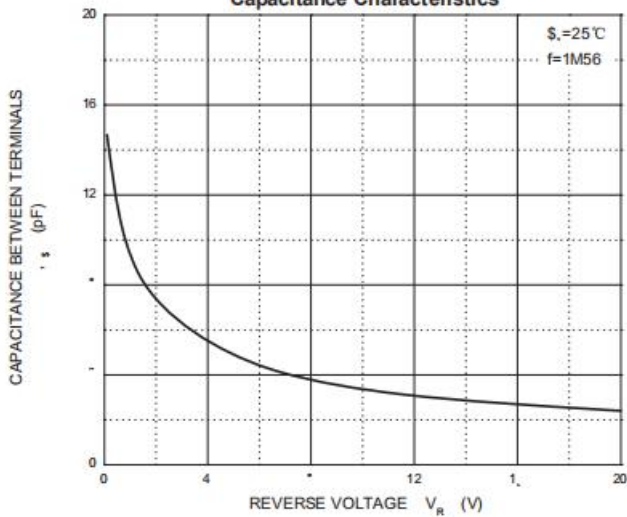
Forward Characteristics



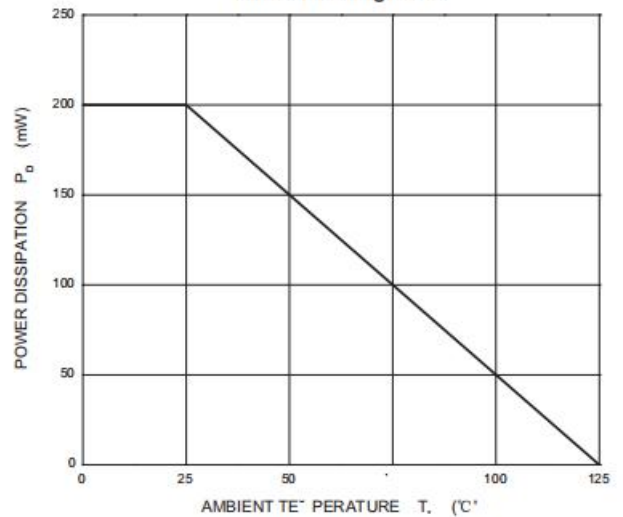
Reverse Characteristics



Capacitance Characteristics



Power Derating Curve

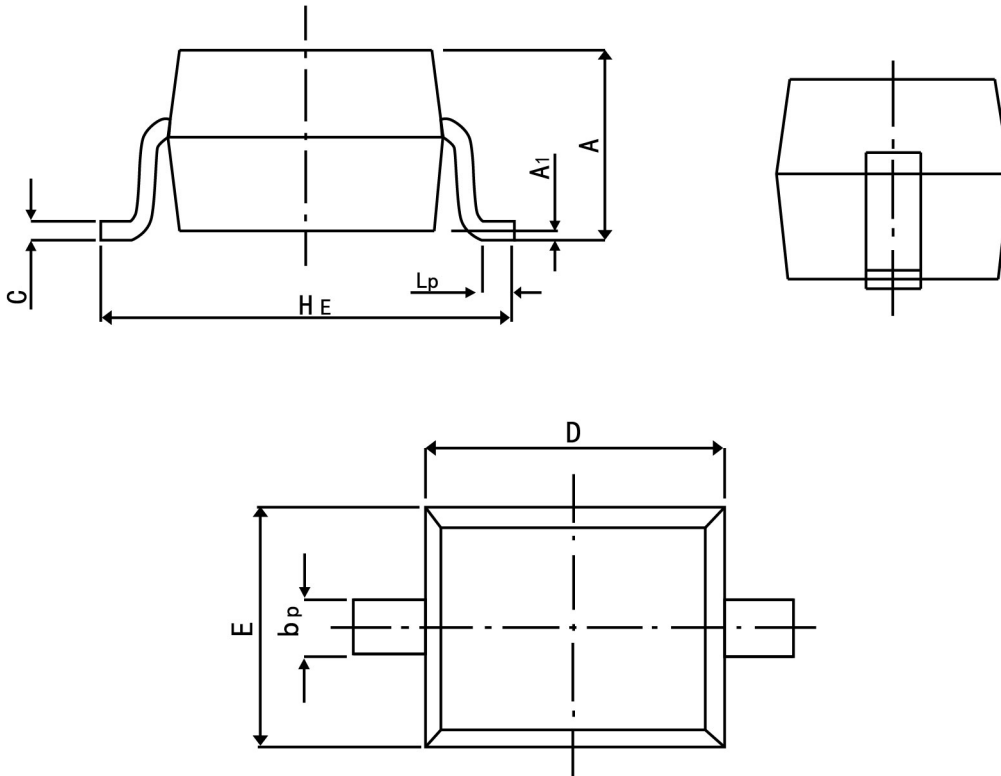




## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



Symbol	Dimension in Millimeters	
	Min	Max
A	0.90	1.20
bp	0.25	0.40
C	0.10	0.15
D	1.60	1.80
E	1.15	1.35
HE	2.30	2.80
A1	0.01	0.10
Lp	0.20	0.50